BGA7351

50 MHz to 500 MHz high linearity Si variable gain amplifier; 28 dB gain range

Rev. 2 — 19 December 2012 Product data sheet

1. Product profile

1.1 General description

The BGA7351 MMIC is a dual independently digitally controlled IF Variable Gain Amplifier (VGA) operating from 50 MHz to 500 MHz. Each IF VGA amplifies with a gain range of 28 dB and at its maximum gain setting delivers 16.5 dBm output power at 1 dB gain compression and a superior linear performance.

The BGA7351 Dual IF VGA is optimized for a differential gain error of less than ±0.1 dB for accurate gain control and has a total integrated gain error of less than ±0.3 dB. Moreover it meets the demanding phase error requirements for GSM. BGA7351 has less than 3.0° phase error over the full gain range of 28 dB.

The gain controls of each amplifier are separate digital gain-control word, which is provided externally through two sets of 5 bits.

The BGA7351 is housed in a 32 pins 5 mm × 5 mm leadless HVQFN32 package.

1.2 Features and benefits

- Dual independent digitally controlled 28 dB gain range VGAs, with 5-bit control interface
- 50 MHz to 500 MHz frequency operating range
- Gain step size: 1 dB ± 0.1 dB
- 22 dB power gain
- Fast gain stage switching capability
- 16.5 dBm output power at 1 dB gain compression
- 46 dBm third order intercept point
- Constant third order intercept point over output power
- –85 dBc second harmonic level
- Excellent noise figure of 6 dB
- 5 V single supply operation with power-down control
- Logic-level shutdown control pin reduces supply current
- Excellent ESD protection at all pins
- Moisture sensitivity level 1
- Unconditionally stable
- Excellent differential integrated gain and phase error
- Compliant to Directive 2002/95/EC, regarding Restriction of Hazardous Substances (RoHS)

1.3 Applications

- Compatible with GSM / W-CDMA / WiMAX / LTE base-station infrastructure / multi carrier systems
- Multi channel receivers
- General use for ADC driver applications

1.4 Quick reference data

Table 1. Quick reference data

A_EN = "1"; B_EN = "1" (VGA enabled). Typical values at V_{CC} = 5 V; I_{CC} = 280 mA; Tuned for f_{IF} = 172 MHz; B = 60 MHz; T_{case} = 25 °C; Differential input resistance matched to 150 Ω; Differential output resistance matched to 200 Ω; unless otherwise specified; see Section 11 "Application information".

Symbol	Parameter	Conditions		Min	Typ	Max	Unit
V_{CC}	supply voltage	$V_{CC(A)} + V_{CC(B)}$		4.75	5	5.25	V
I_{CC}	supply current	$I_{CC(A)} + I_{CC(B)}$					
		A_EN = "0"; B_EN = "0"		-	3	5	mA
		A_EN = "1"; B_EN = "1"		-	280	300	mA
G_p	power gain	maximum gain	[1]	21	22	23	dB
		minimum gain	[2]	–7	–6	–5	dB
$R_{i(dif)}$	differential input resistance			120	150	180	Ω
$R_{o(dif)}$	differential output resistance			140	180	220	Ω
NF	noise figure	maximum gain	[1]	-	6	7	dB
		increased rate per gain step		-	0.8	1	dB
$IP3_O$	output third-order intercept point	gain step 14	[3][4]	-	46	-	dBm
$P_{L(1dB)}$	output power at 1 dB gain compression	upper 5 gain steps	[1][5]	-	16.5	-	dBm
α_{2H}	second harmonic level	gain step 14	[4][6]	-	–85	-	dBc
$E_{G(dif)}$	differential gain error			-	± 0.1	-	dB
$E_{\varphi(dif)}$	differential phase error	upper 12 dB gain range		-	1.0	-	deg
		per gain step (for all consecutive gain steps)		-	0.5	-	deg

[1] Maximum gain; gain code = 00000.

[2] Minimum gain; gain code = 11100.

[3] P_L = 2 dBm per tone; spacing = 2 MHz (f_1 = 171 MHz; f_2 = 173 MHz)

[4] Gain code = 01110.

[5] Gain code = 00000, 00001, 00010, 00011, 00100.

[6] P_L = 2 dBm one tone (f = 86 MHz; f_{meas} = 172 MHz)

2. Pinning information

2.1 Pinning

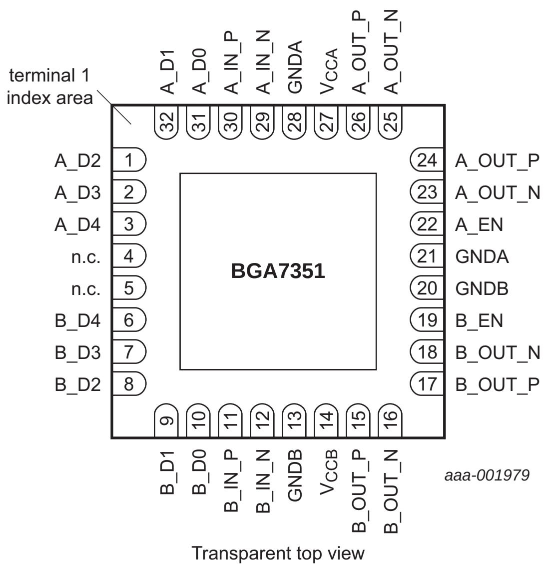


Fig 1. Pin configuration SOT617-1

2.2 Pin description

Table 2. Pin description

Symbol	Pin	Description
A_D2	1	MSB – 2 for gain control interface of channel A
A_D3	2	MSB – 1 for gain control interface of channel A
A_D4	3	MSB for gain control interface of channel A
n.c.	4	not connected [1]
n.c.	5	not connected [1]
B_D4	6	MSB for gain control interface of channel B
B_D3	7	MSB – 1 for gain control interface of channel B
B_D2	8	MSB – 2 for gain control interface of channel B
B_D1	9	LSB + 1 for gain control interface of channel B
B_D0	10	LSB for gain control interface of channel B
B_IN_P	11	channel B positive input [2]
B_IN_N	12	channel B negative input [2]
GNDB	13, 20	ground for channel B
V_{CCB}	14	supply voltage for channel B
B_OUT_P	15, 17	channel B positive output [2]
B_OUT_N	16, 18	channel B negative output [2]
B_EN	19	power enable pin for channel B
GNDA	21, 28	ground for channel A

Table 2. Pin description *...continued*

Symbol	Pin	Description
A_EN	22	power enable pin for channel A
A_OUT_N	23, 25	channel A negative output [2]
A_OUT_P	24, 26	channel A positive output [2]
V_{CCA}	27	supply voltage for channel A
A_IN_N	29	channel A negative input [2]
A_IN_P	30	channel A positive input [2]
A_D0	31	LSB for gain control interface of channel A
A_D1	32	LSB + 1 for gain control interface of channel A
GND	GND paddle	RF ground and DC ground [3]

[1] Pin to be left open.

[2] Each channel should be independently enabled with logic HIGH and disabled with logic LOW.

[3] The center metal base of the SOT617-1 also functions as heatsink for the VGA.

3. Ordering information

Table 3. Ordering information

Type number	Package		
	Name	Description	Version
BGA7351	HVQFN32	plastic thermal enhanced very thin quad flat package; no leads; 32 terminals; body 5 × 5 × 0.85 mm	SOT617-1

4. Functional diagram

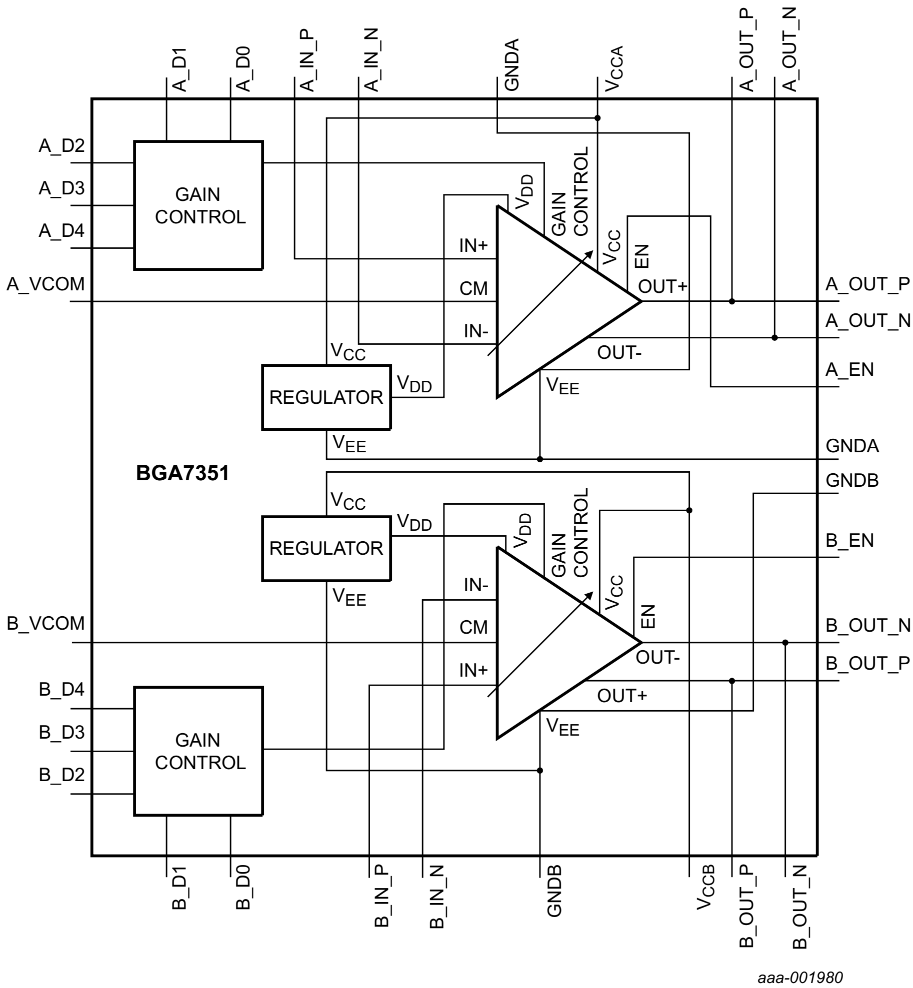


Fig 2. Functional diagram

5. Enable control

Table 4. Enable / disable control settings

Mode	Function description	Mode description	Enable		V_{EN} (V)		I_{EN} (μA)	
			A_EN	B_EN	Min	Max	Min	Max
A_EN, B_EN	VGA function off	Disable	"0"	"0"	0	0.8	-	1
A_EN, B_EN	VGA in operating mode	Enable	"1"	"1"	1.6	5.25	-	1

6. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
$V_{CC(A)}$	supply voltage (A)		[1]	-	6	V
$V_{CC(B)}$	supply voltage (B)		[1]	-	6	V
V_{AEN}	voltage on pin A_EN			–0.6	+6	V
V_{BEN}	voltage on pin B_EN			–0.6	+6	V
V_{AD0}	voltage on pin A_D0			–0.6	+6	V
V_{AD1}	voltage on pin A_D1			–0.6	+6	V
V_{AD2}	voltage on pin A_D2			–0.6	+6	V
V_{AD3}	voltage on pin A_D3			–0.6	+6	V
V_{AD4}	voltage on pin A_D4			–0.6	+6	V
V_{BD0}	voltage on pin B_D0			–0.6	+6	V
V_{BD1}	voltage on pin B_D1			–0.6	+6	V
V_{BD2}	voltage on pin B_D2			–0.6	+6	V
V_{BD3}	voltage on pin B_D3			–0.6	+6	V
V_{BD4}	voltage on pin B_D4			–0.6	+6	V
V_{AIN}	voltage on pin A_IN			–0.6	+6	V
V_{BIN}	voltage on pin B_IN			–0.6	+6	V
$P_{i(RF)}$	RF input power			-	20	dBm
T_{case}	case temperature			–40	+85	°C
T_j	junction temperature			-	150	°C
V_{ESD}	electrostatic discharge voltage	Human Body Model (HBM); According JEDEC standard 22-A114E		-	4000	V
		Charged Device Model (CDM); According JEDEC standard 22-C101B		-	2000	V
		Machine Model (MM); According JEDEC standard 22-A115		-	400	V

[1] Caution: All digital pins may not exceed V_{CC} as the internal ESD circuit can be damaged. To prevent this it is recommended that V_{AEN} and V_{BEN} are limited to a maximum of 5 mA.

7. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions	Typ	Unit
$R_{th(j\text{-}case)}$	thermal resistance from junction to case	T_{case} = 85 °C; V_{CC} = 5 V; I_{CC} = 280 mA	7	K/W

8. Static characteristics

Table 7. Characteristics

A_EN = "1"; B_EN = "1" (both channels enabled). Typical values at V_{CC} = 5 V; T_{case} = 25 °C; unless otherwise specified.

Symbol	Parameter	Conditions		Min	Typ	Max	Unit
V_{CC}	supply voltage	$V_{CC(A)} + V_{CC(B)}$		4.75	5	5.25	V
I_{CC}	supply current	$I_{CC(A)} + I_{CC(B)}$					
		A_EN = "0"; B_EN = "0"		-	3	5	mA
		A_EN = "1"; B_EN = "1"		-	280	300	mA
V_{IH}	HIGH-level input voltage		[1]	1.6	-	5.25	V
V_{IL}	LOW-level input voltage		[1]	-	-	0.8	V
P_L	power dissipation			-	1.4	1.6	W

[1] Voltage on the control pins.

9. Dynamic characteristics

Table 8. Characteristics

A_EN = "1"; B_EN = "1" (VGA enabled). Typical values at V_{CC} = 5 V; I_{CC} = 280 mA; Tuned for f_{IF} = 172 MHz; B = 60 MHz; T_{case} = 25 °C; Differential input resistance matched to 150 Ω; Differential output resistance matched to 200 Ω; unless otherwise specified; see Section 11 "Application information".

Symbol	Parameter	Conditions		Min	Typ	Max	Unit
G_p	power gain	maximum gain	[1]				
		f = 50 MHz; B = 30 MHz		-	22.5	-	dB
		f = 172 MHz; B = 60 MHz		21	22	23	dB
		f = 250 MHz; B = 60 MHz		-	21.5	-	dB
		minimum gain	[2]				
		f = 50 MHz; B = 30 MHz		-	−5.5	-	dB
		f = 172 MHz; B = 60 MHz		−7	−6	−5	dB
		f = 250 MHz; B = 60 MHz		-	−6.5	-	dB
ΔG_{adj}	gain adjustment range		[1]	-	28	-	dB
G_{step}	gain step			-	1	-	
G_{flat}	gain flatness		[1]	-	0.1	-	dB
$E_{G(dif)}$	differential gain error			-	± 0.1	-	dB
$E_{G(itg)}$	integrated gain error	upper 12 dB gain range		-	± 0.2	-	dB
		full gain range		-	± 0.3	-	dB
$E_{\varphi(dif)}$	differential phase error	upper 12 dB gain range		-	1.0	-	deg
		per gain step (for all consecutive gain steps)		-	0.5	-	deg
		full gain range		-	3.0	-	deg
$t_{s(step)G}$	gain step settling time	per 1.5 dB of steady state		-	5	15	ns
		per 0.1 dB of steady state		-	20	40	ns
$\Delta t_{d(grp)}$	group delay time variation	B = 30 MHz		-	86	-	ps

Table 8. Characteristics *...continued*

A_EN = "1"; B_EN = "1" (VGA enabled). Typical values at V_{CC} = 5 V; I_{CC} = 280 mA; Tuned for f_{IF} = 172 MHz; B = 60 MHz; T_{case} = 25 °C; Differential input resistance matched to 150 Ω; Differential output resistance matched to 200 Ω; unless otherwise specified; see Section 11 "Application information".

Symbol	Parameter	Conditions		Min	Typ	Max	Unit
t_{pu}	power-up time			-	-	1	µs
$R_{i(dif)}$	differential input resistance			120	150	180	Ω
$R_{o(dif)}$	differential output resistance			140	180	220	Ω
$\alpha_{isol(ch-ch)}$	isolation between channels			50	-	-	dB
CMRR	common-mode rejection ratio			40	-	-	dB
$IP3_O$	output third-order intercept point	gain step 14	[3]				
		f = 50 MHz	[4]	-	47	-	dBm
		f = 172 MHz	[5]	-	46	-	dBm
		f = 250 MHz	[6]	-	41	-	dBm
		upper 5 gain steps	[7]				
		f = 50 MHz	[4]	-	48	-	dBm
		f = 172 MHz	[5]	-	44	-	dBm
		f = 250 MHz	[6]	-	41	-	dBm
$IP2_O$	output second-order intercept point	upper 5 gain steps	[7]				
		f = 50 MHz	[8]	-	78	-	dBm
		f = 172 MHz	[9]	-	73	-	dBm
		f = 250 MHz	[10]	-	65	-	dBm
$P_{L(1dB)}$	output power at 1 dB gain compression	upper 5 gain steps	[7]				
		f = 50 MHz		-	16.8	-	dBm
		f = 172 MHz		-	16.5	-	dBm
		f = 250 MHz		-	15.8	-	dBm
α_{2H}	second harmonic level	P_L = 2 dBm					
		gain step 14	[3][11]	-	−85	-	dBc
		upper 5 gain steps	[7][11]	-	−83	-	dBc
		P_L = 5 dBm					
		gain step 14	[3][12]	-	−82	-	dBc
		upper 5 gain steps	[7][12]	-	−80	-	dBc
NF	noise figure	maximum gain	[1]	-	6	7	dB
		increase rate per gain step		-	0.8	1	dB

[1] Maximum gain; gain code = 00000.

[2] Minimum gain; gain code = 11100.

[3] Gain code = 01110.

[4] P_L = 2 dBm per tone; spacing = 2 MHz (f_1 = 49 MHz; f_2 = 51 MHz)

[5] P_L = 2 dBm per tone; spacing = 2 MHz (f_1 = 171 MHz; f_2 = 173 MHz)

[6] P_L = 2 dBm per tone; spacing = 2 MHz (f_1 = 249 MHz; f_2 = 251 MHz)

[7] Gain code = 00000, 00001, 00010, 00011, 00100.

[8] P_L = 2 dBm per tone (f_1 = 24 MHz; f_2 = 74 MHz; f_{meas} = 50 MHz)

[9] P_L = 2 dBm per tone (f_1 = 82 MHz; f_2 = 90 MHz; f_{meas} = 172 MHz)

[10] P_L = 2 dBm per tone (f_1 = 120 MHz; f_2 = 130 MHz; f_{meas} = 250 MHz)

[11] P_L = 2 dBm one tone (f = 86 MHz; f_{meas} = 172 MHz)

[12] P_L = 5 dBm one tone (f = 86 MHz; f_{meas} = 172 MHz)

Table 9. Gain control

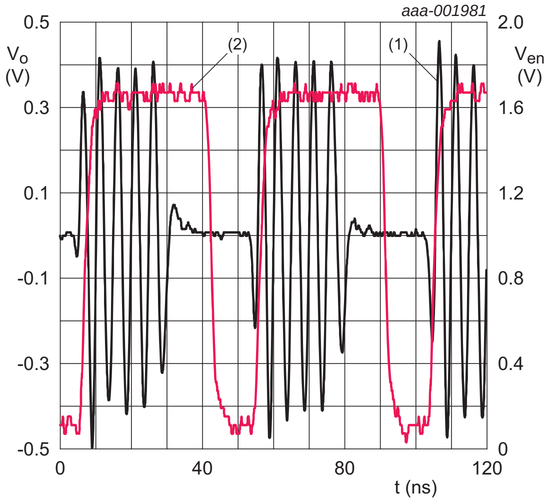
gain step	input to either A_D0 to A_D4 pins or B_D0 to B_D4 pins	nominal power gain (dB)
0	00000	22
1	00001	21
2	00010	20
3	00011	19
4	00100	18
5	00101	17
6	00110	16
7	00111	15
8	01000	14
9	01001	13
10	01010	12
11	01011	11
12	01100	10
13	01101	9
14	01110	8
15	01111	7
16	10000	6
17	10001	5
18	10010	4
19	10011	3
20	10100	2
21	10101	1
22	10110	0
23	10111	–1
24	11000	–2
25	11001	–3
26	11010	–4
27	11011	–5
28	11100	–6
-	> 11100	–6

10. Moisture sensitivity

Table 10. Moisture sensitivity level

Test methodology	Class
JESD-22-A113	1

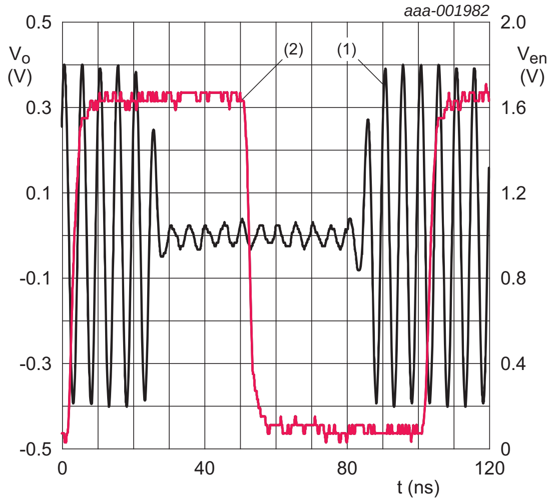
11. Application information



(1) V_O

(2) V_{en}

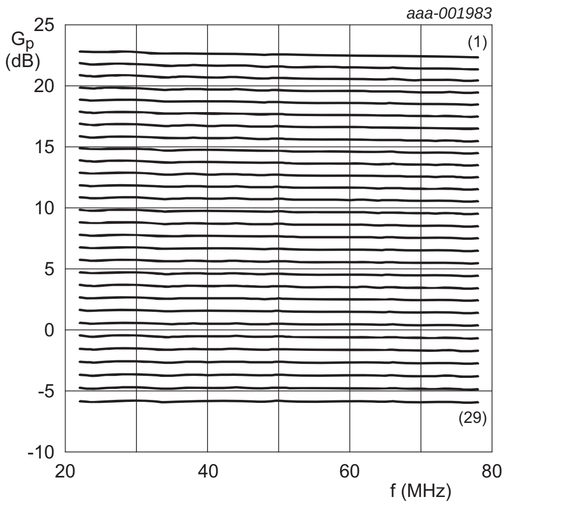
Fig 3. Enable time response



(1) V_O

(2) V_{en}

Fig 4. Gain step response from min. to max. gain

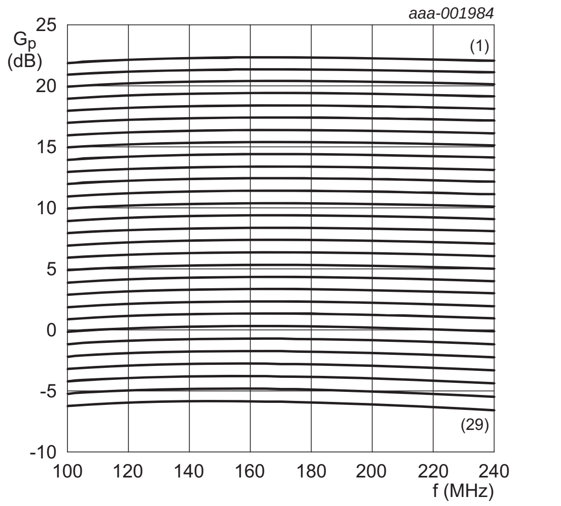


Tuned for f_{IF} = 50 MHz; P_L = 5 dBm; step size 1 dB.

(1) gain step 0 (maximum gain)

(29) gain step 28 (minimum gain)

Fig 5. Power gain as a function of frequency

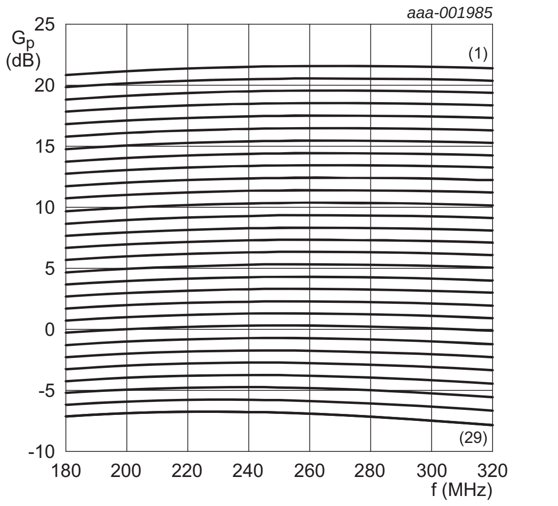


Tuned for f_{IF} = 172 MHz; P_L = 5 dBm; step size 1 dB.

(1) gain step 0 (maximum gain)

(29) gain step 28 (minimum gain)

Fig 6. Power gain as a function of frequency

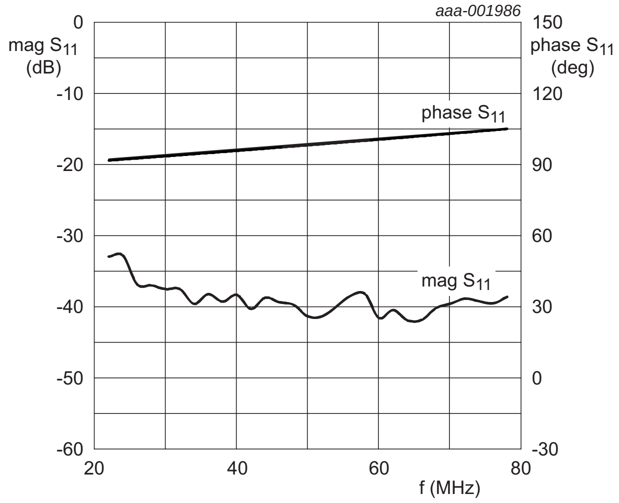


Tuned for f_{IF} = 250 MHz; P_L = 5 dBm; step size 1 dB.

(1) gain step 0 (maximum gain)

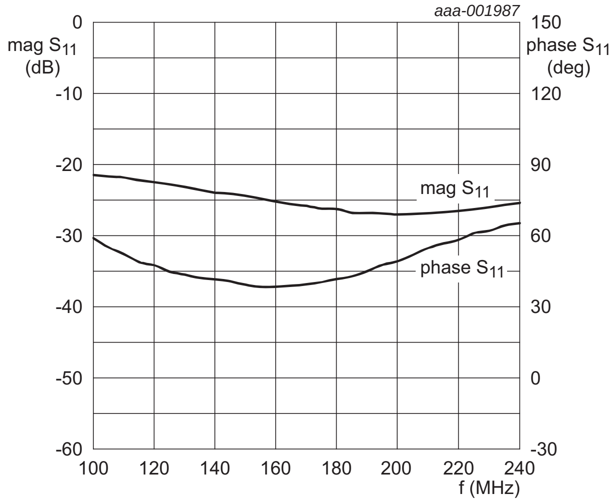
(29) gain step 28 (minimum gain)

Fig 7. Power gain as a function of frequency



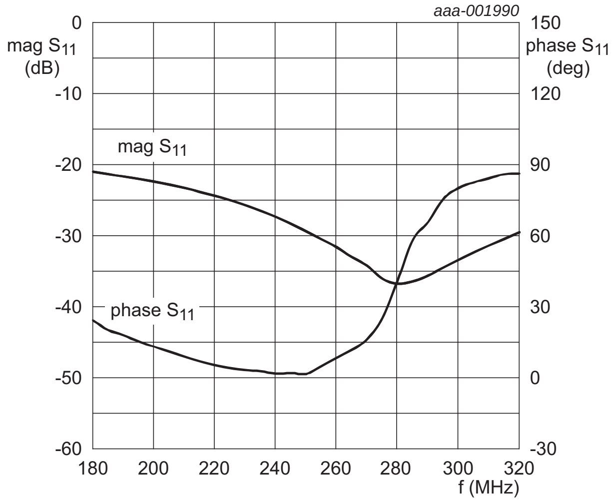
Tuned for f_{IF} = 50 MHz; measured at gain step 0 (maximum gain).

Fig 8. S_{11} as a function of frequency



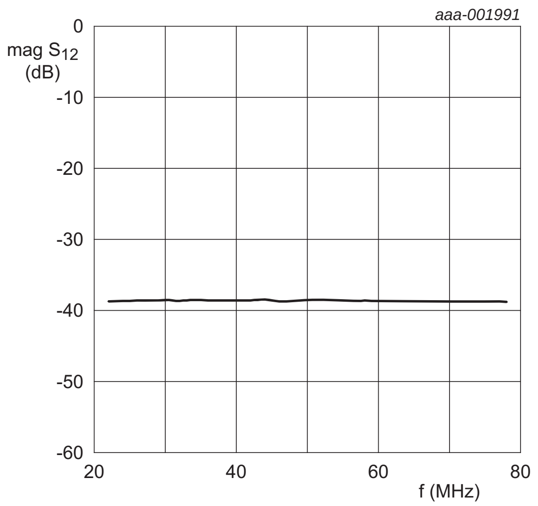
Tuned for f_{IF} = 172 MHz; measured at gain step 0 (maximum gain).

Fig 9. S_{11} as a function of frequency



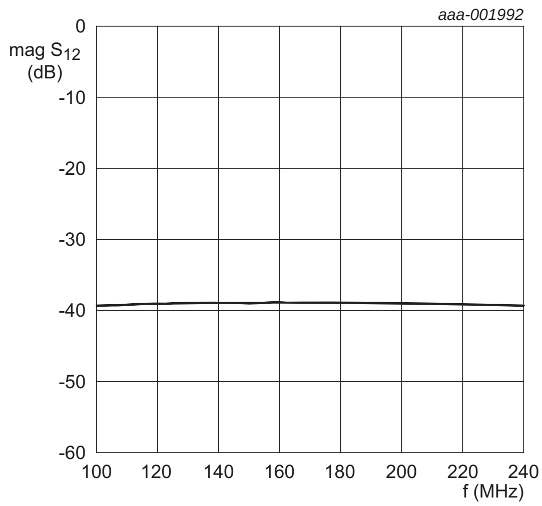
Tuned for f_{IF} = 250 MHz; measured at gain step 0 (maximum gain).

Fig 10. S_{11} as a function of frequency



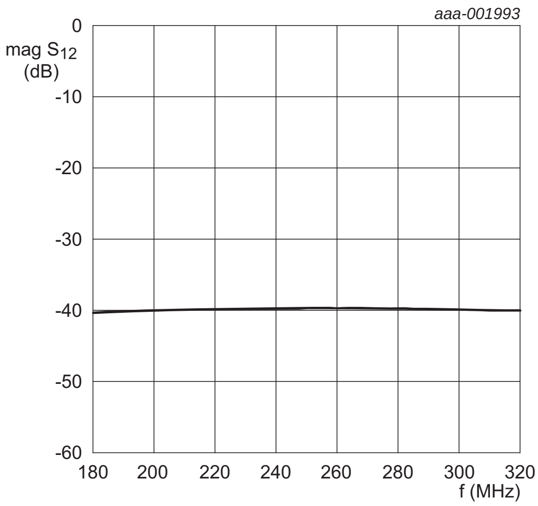
Tuned for f_{IF} = 50 MHz; measured at gain step 0 (maximum gain).

Fig 11. S_{12} as a function of frequency



Tuned for f_{IF} = 172 MHz; measured at gain step 0 (maximum gain).

Fig 12. S_{12} as a function of frequency



Tuned for f_{IF} = 250 MHz; measured at gain step 0 (maximum gain).

Fig 13. S_{12} as a function of frequency

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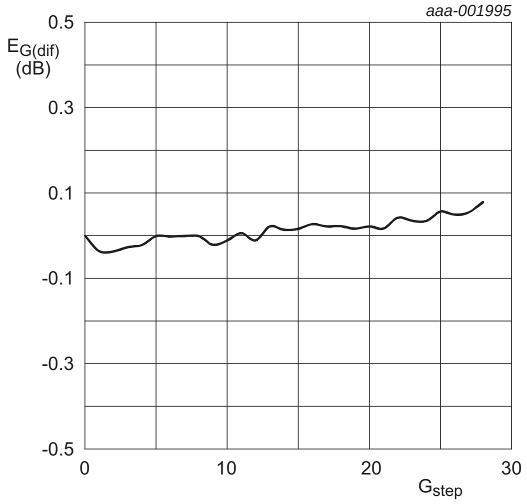
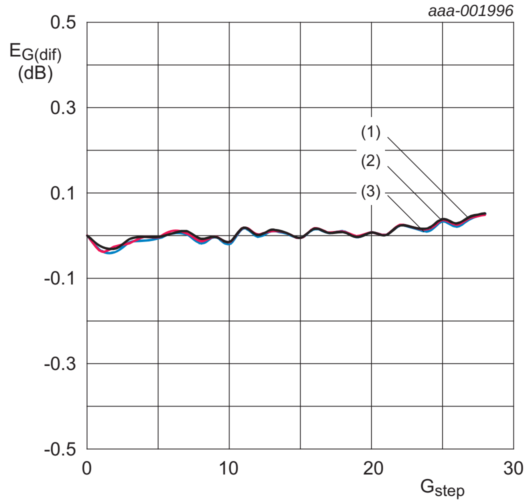


Tuned for f_{IF} = 50 MHz.

Fig 14. Differential gain error as a function of gain step



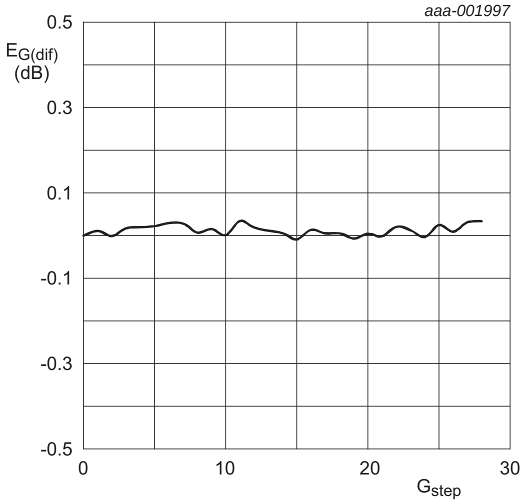
Tuned for f_{IF} = 172 MHz.

(1) T_{amb} = −40 °C

(2) T_{amb} = +25 °C

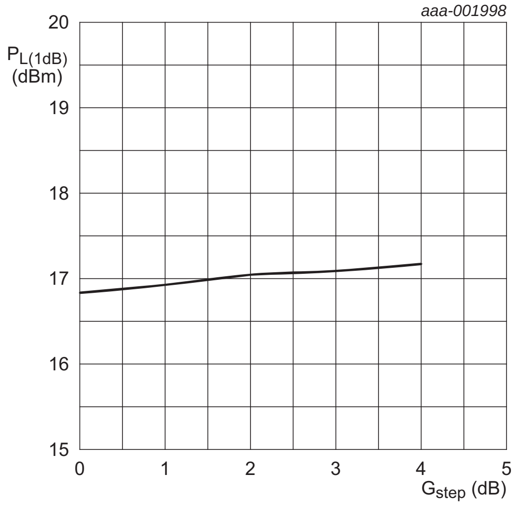
(3) T_{amb} = +85 °C

Fig 15. Differential gain error as a function of gain step



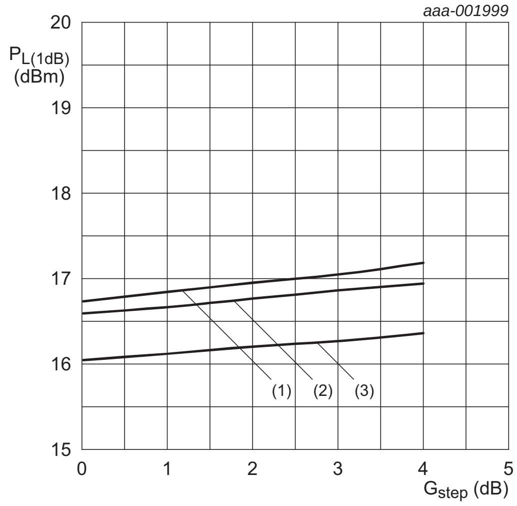
Tuned for f_{IF} = 250 MHz.

Fig 16. Differential gain error as a function of gain step



Tuned for f_{IF} = 50 MHz.

Fig 17. output power at 1 dB gain compression as a function of gain step



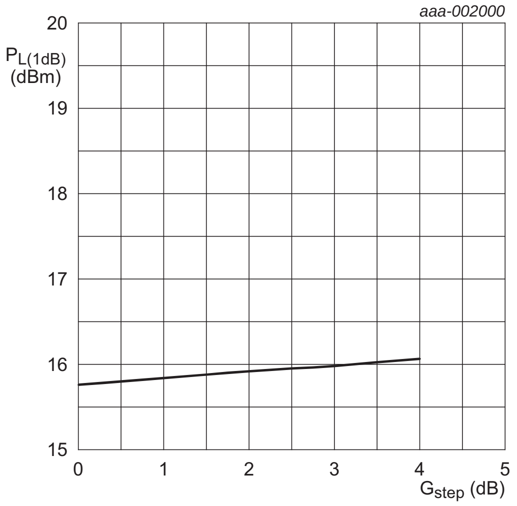
Tuned for f_{IF} = 172 MHz.

(1) T_{amb} = −40 °C

(2) T_{amb} = +25 °C

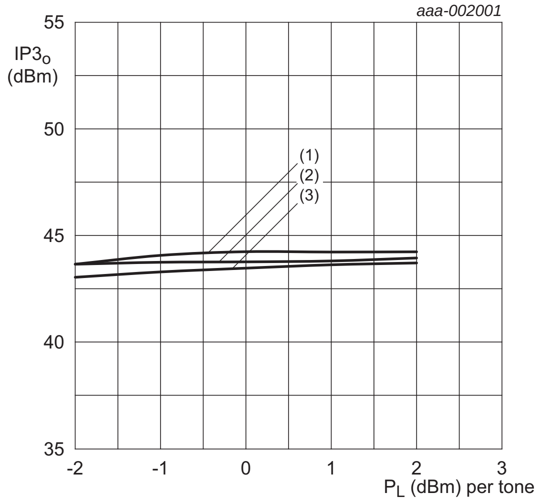
(3) T_{amb} = +85 °C

Fig 18. output power at 1 dB gain compression as a function of gain step



Tuned for f_{IF} = 250 MHz.

Fig 19. output power at 1 dB gain compression as a function of gain step



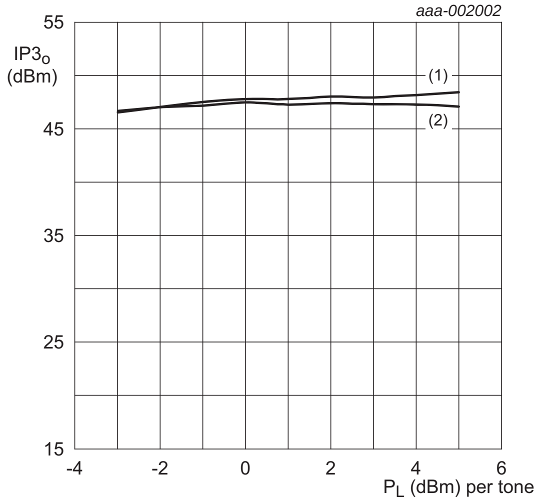
Tuned for f_{IF} = 172 MHz; measured at gain step 0 (maximum gain).

(1) T_{amb} = –40 °C

(2) T_{amb} = +25 °C

(3) T_{amb} = +85 °C

Fig 20. Output third order intercept point as a function of output power per tone

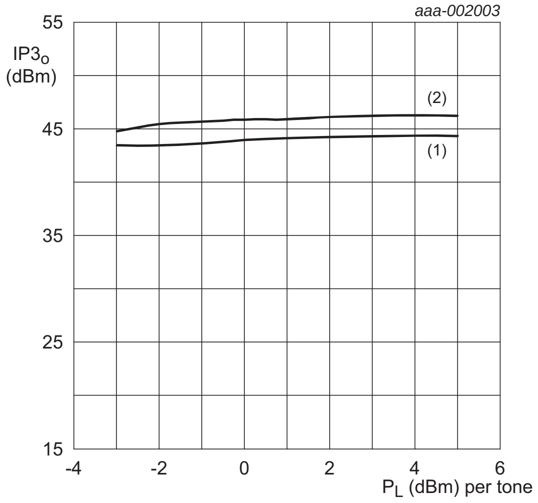


Tuned for f_{IF} = 50 MHz.

(1) gain step 0

(2) gain step 14

Fig 21. Output third order intercept point as a function of output power per tone

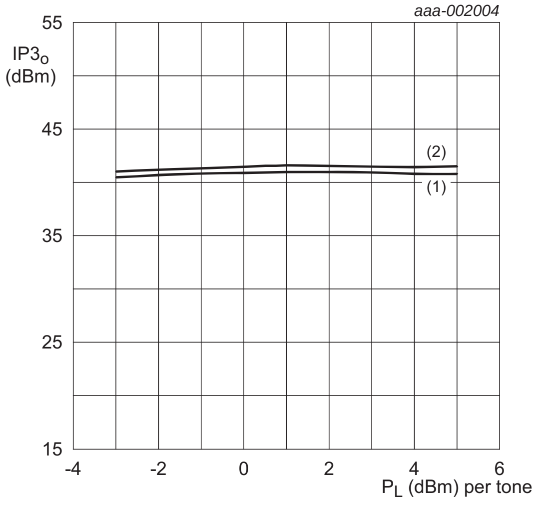


Tuned for f_{IF} = 172 MHz.

(1) gain step 0

(2) gain step 14

Fig 22. Output third order intercept point as a function of output power per tone

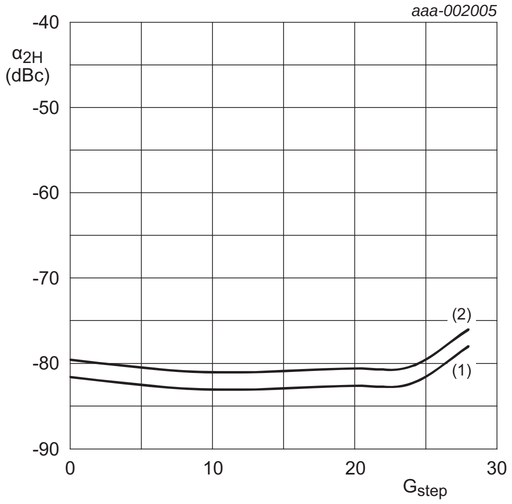


Tuned for f_{IF} = 250 MHz.

(1) gain step 0

(2) gain step 14

Fig 23. Output third order intercept point as a function of output power per tone

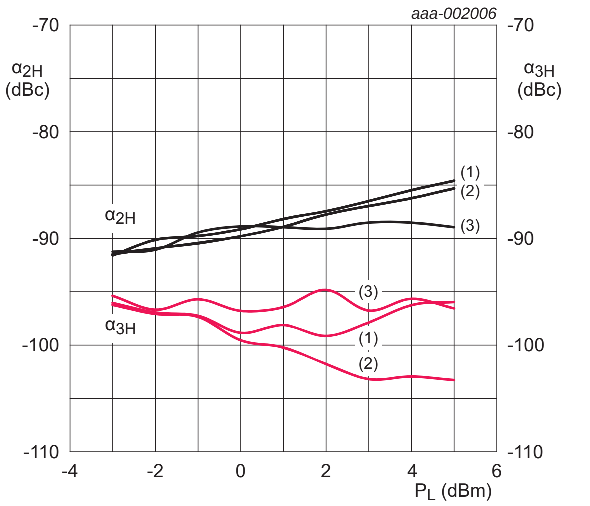


Tuned for f_{IF} = 86 MHz; f_{2H} = 172 MHz; f_{3H} = 258 MHz.

(1) P_L = 2 dBm

(2) P_L = 5 dBm

Fig 24. Second harmonic level as a function of gain step



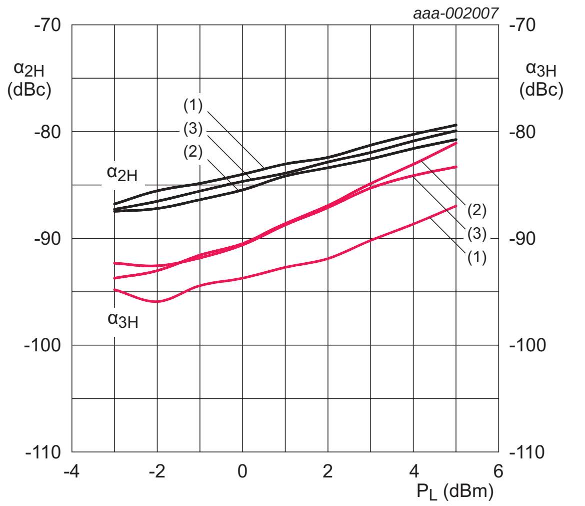
Tuned for f_{IF} = 50 MHz; f_{2H} = 100 MHz; f_{3H} = 150 MHz; T_{amb} = 25 °C.

(1) gain step 0

(2) gain step 14

(3) gain step 24

Fig 25. Second harmonic level and third harmonic level as a function of output power



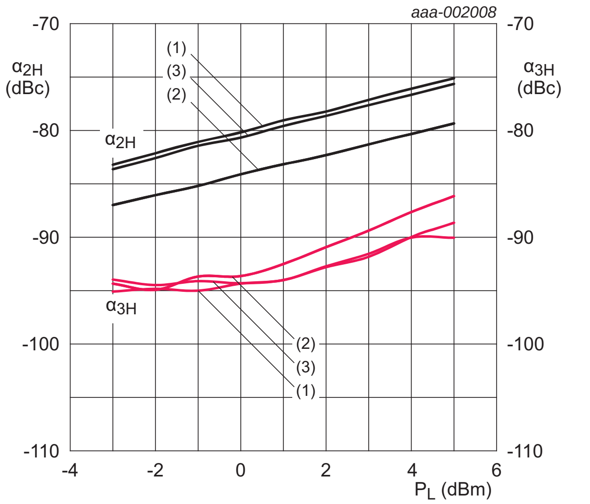
Tuned for f_{IF} = 86 MHz; f_{2H} = 172 MHz; f_{3H} = 258 MHz; T_{amb} = 25 °C.

(1) gain step 0

(2) gain step 14

(3) gain step 24

Fig 26. Second harmonic level and third harmonic level as a function of output power



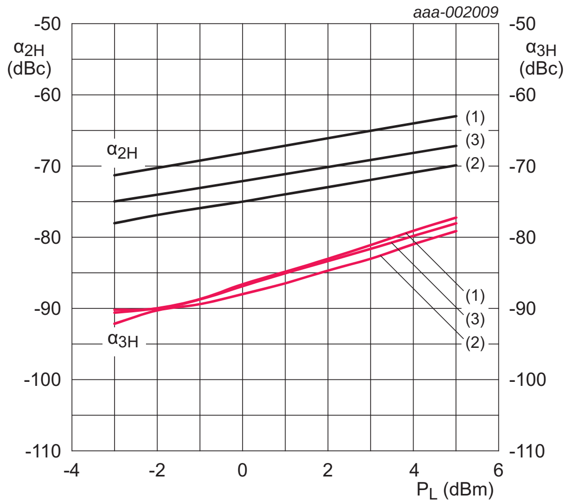
Tuned for f_{IF} = 172 MHz; f_{2H} = 358 MHz; f_{3H} = 530 MHz; T_{amb} = 25 °C.

(1) gain step 0

(2) gain step 14

(3) gain step 24

Fig 27. Second harmonic level and third harmonic level as a function of output power



Tuned for f_{IF} = 250 MHz; f_{2H} = 500 MHz; f_{3H} = 750 MHz; T_{amb} = 25 °C.

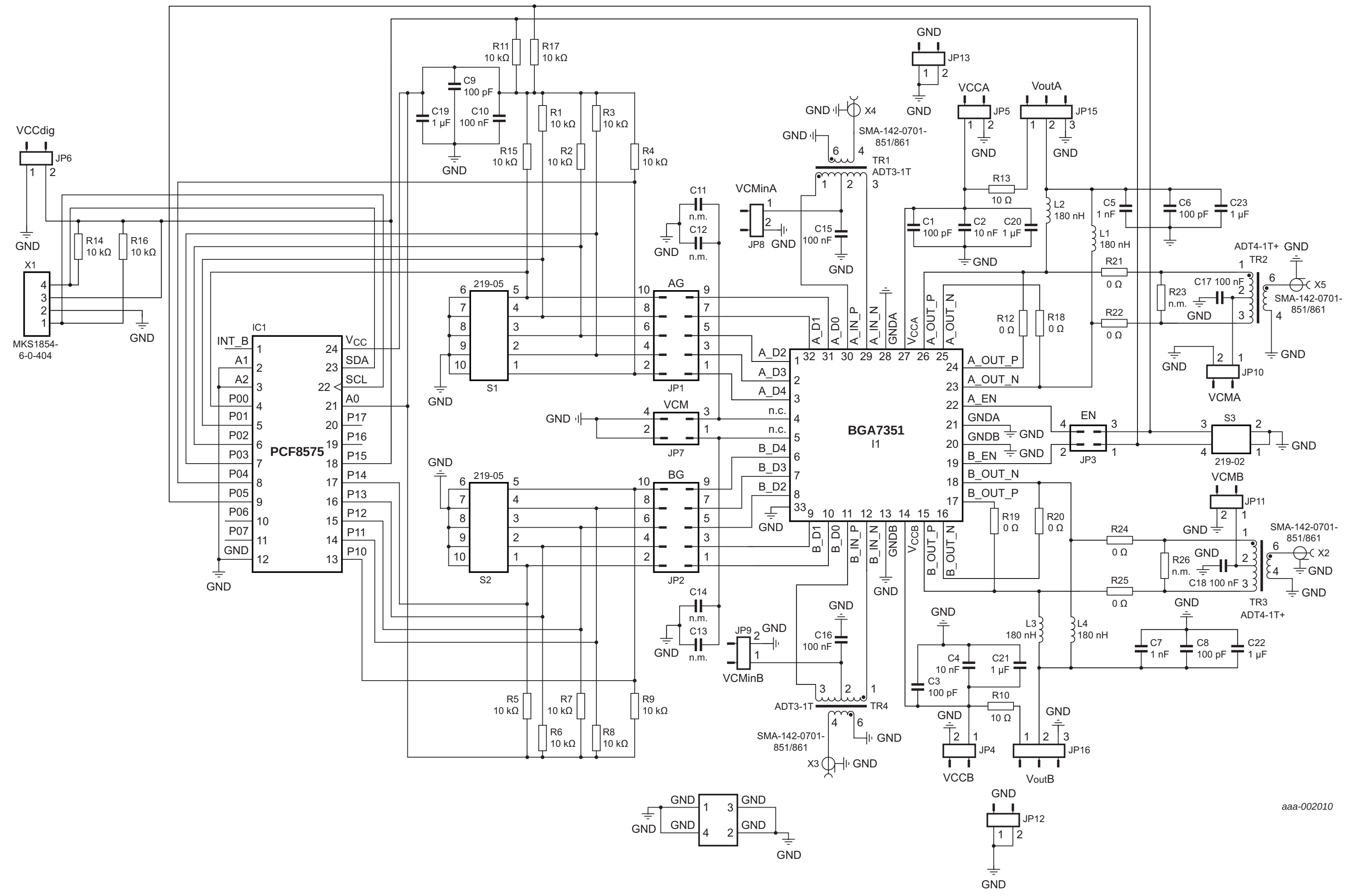
(1) gain step 0

(2) gain step 14

(3) gain step 24

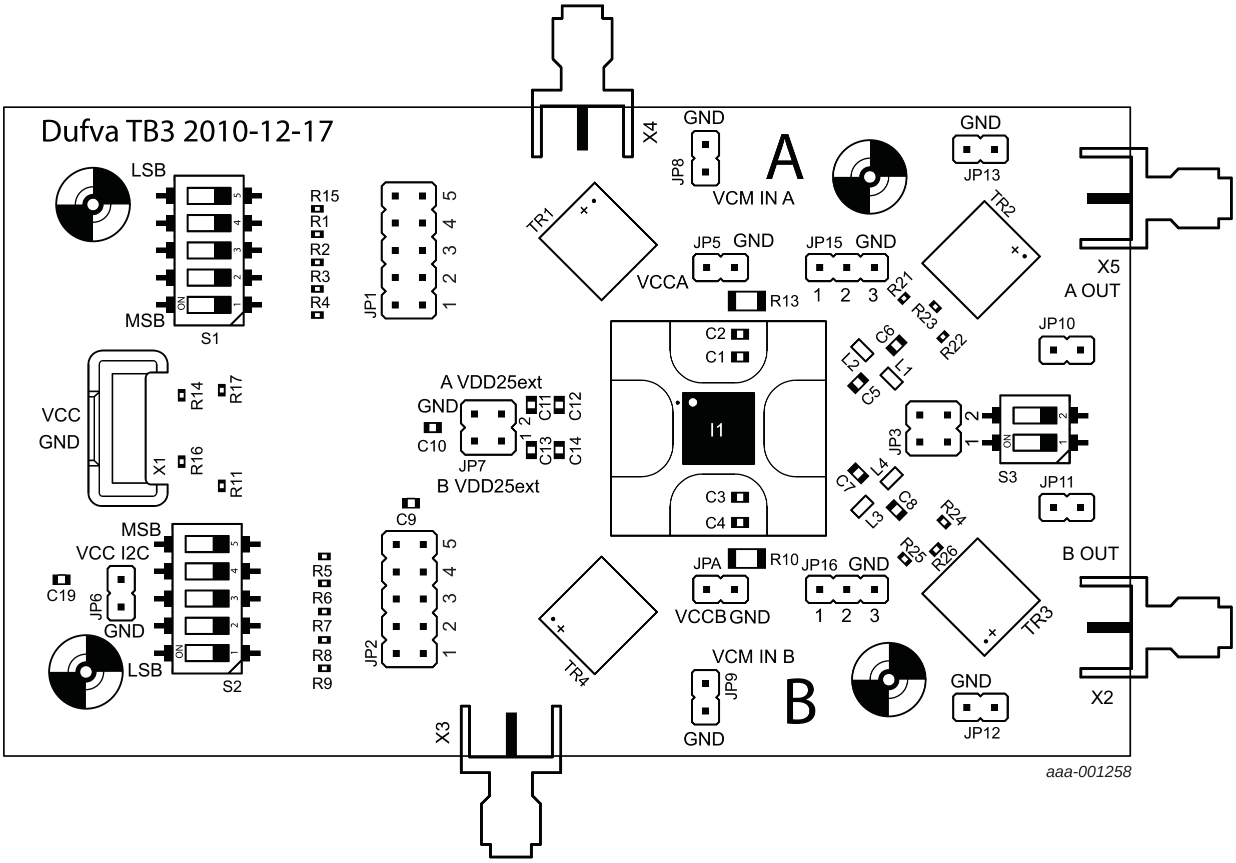
Fig 28. Second harmonic level and third harmonic level as a function of output power

11.1 Application PCB



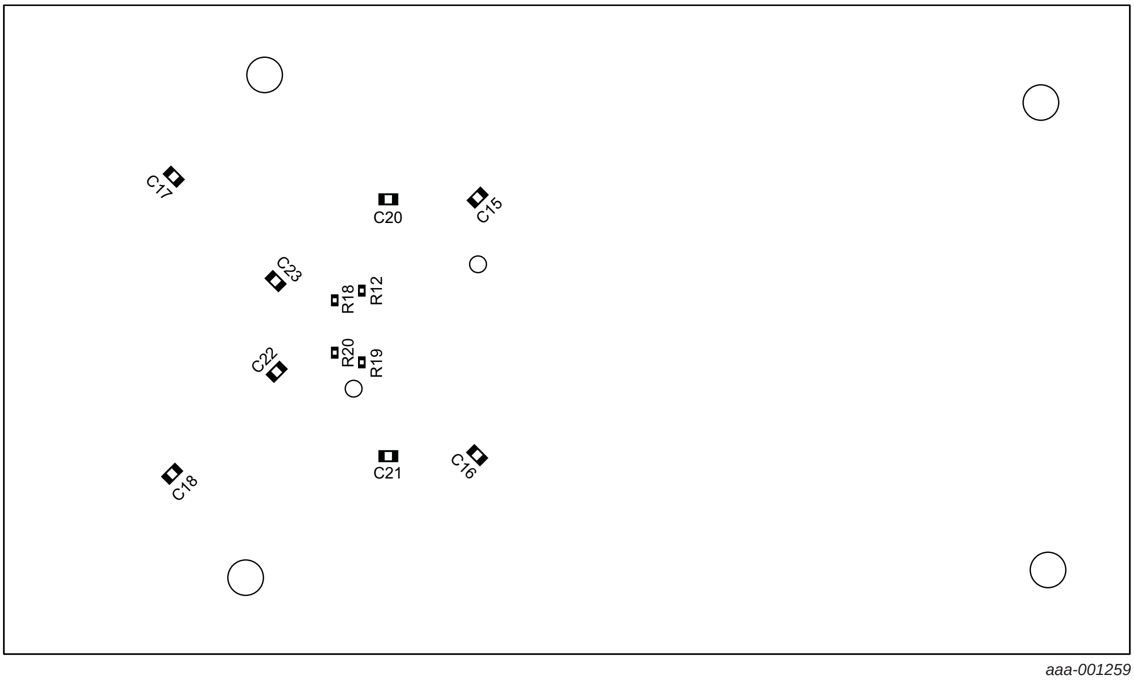
For a list of components see Table 11.

Fig 29. Schematic



For a list of components see Table 11.

Fig 30. Components top side



For a list of components see Table 11.

Fig 31. Components bottom side

Table 11. List of components

See Figure 29, Figure 30 and Figure 31.

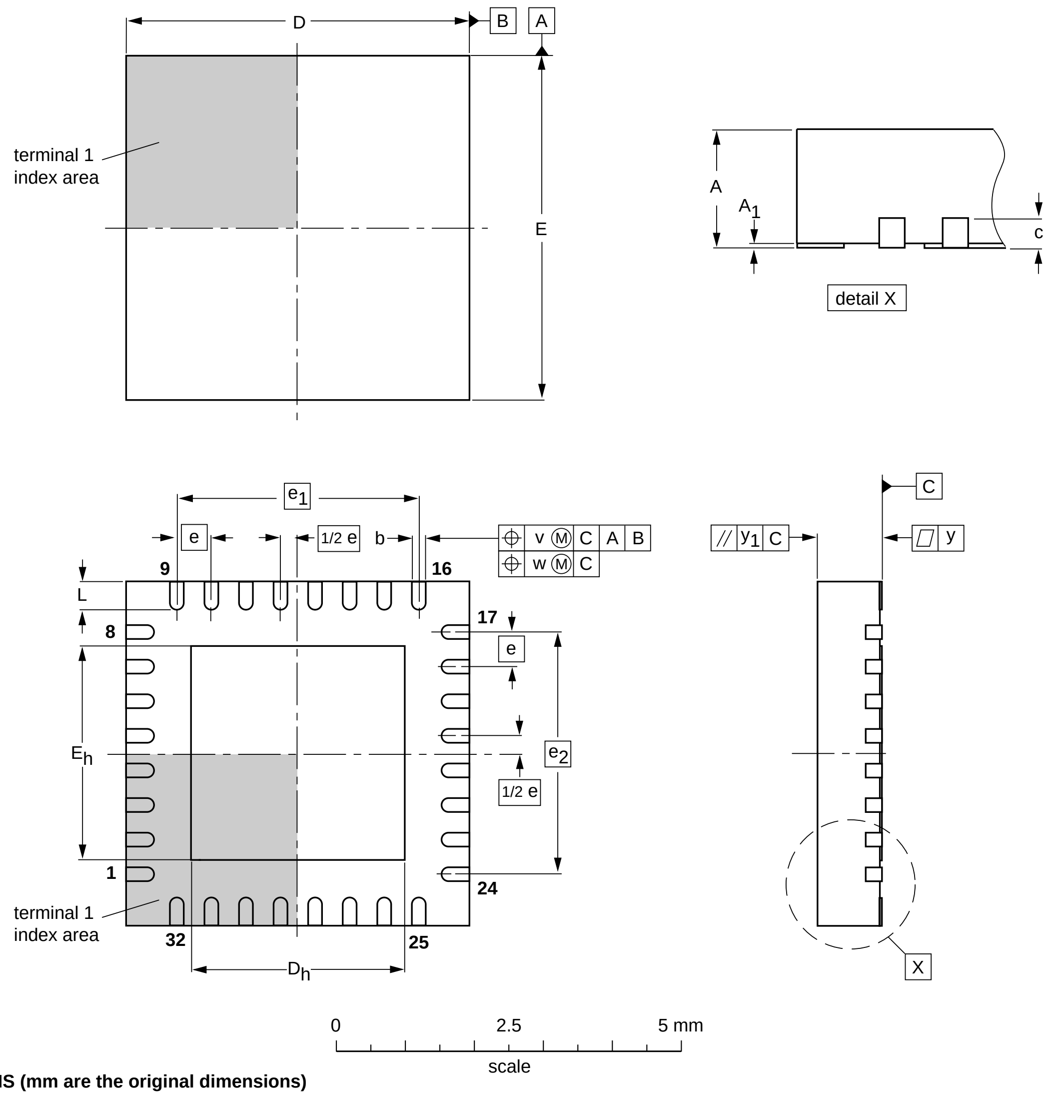
Component	Description	Conditions	Value	Size	Remarks
C1, C3, C6, C8, C9	capacitor		100 pF	0603	
C2, C4	capacitor		10 nF	0603	
C5, C7	capacitor		1 nF	0603	
C10, C15, C16, C17, C18	capacitor		100 nF	0603	
C11	capacitor		-	0603	not mounted
C12	capacitor		-	0603	not mounted
C13	capacitor		-	0603	not mounted
C14	capacitor		-	0603	not mounted
C19, C20, C21, C22, C23	capacitor		1 μF	0603	
I1	BGA7351		-		
JP1	jumper		-	JP5	AG
JP2	jumper		-	JP5	BG
JP3	jumper		-	JP2	EN
JP4	jumper		-	JP2	VCCB
JP5	jumper		-	JP2	VCCA
JP6	jumper		-	JP2	VCCdig
JP7	jumper		-	JP2	VCM
JP8	jumper		-	JP2	VCMinA

Table 11. List of components
See Figure 29, Figure 30 and Figure 31.

Component	Description	Conditions	Value	Size	Remarks
JP9	jumper		-	JP2	VCMinB
JP10	jumper		-	JP2	VCMA
JP11	jumper		-	JP2	VCMB
JP12	jumper		-	JP2	GND
JP13	jumper		-	JP2	GND
JP15	jumper		-	JP3	VoutA
JP16	jumper		-	JP3	VoutB
L1, L2, L3, L4	inductor	f_{IF} = 50 MHz	1200 nH	0603	dependent on PCB layout
		f_{IF} = 172 MHz	150 nH	0603	dependent on PCB layout
		f_{IF} = 250 MHz	56 nH	0603	dependent on PCB layout
R1, R2, R3, R4, R5, R6, R7, R8, R9, R11, R14, R15, R16, R17	resistor		10 kΩ	0402	
R10, R13	resistor		10 Ω	1206	
R12, R18, R19, R20, R21, R22, R24, R25	resistor		0 Ω	0402	
R23, R26	resistor		-	0402	not mounted
S1, S2	DIP-switch		-		CTS-219-05
S3	DIP-switch		-		CTS-219-02
TR1	1:3 transformer		-		Mini Circuits ADT3-1T+
TR2	1:4 transformer		-		Mini Circuits ADT4-1T+
TR3	1:3 transformer		-		Mini Circuits ADT4-1T+
TR4	1:4 transformer		-		Mini Circuits ADT3-1T+
X1	-		-		not mounted
X2	SMA-connector		-		BOUT_P
X3	SMA-connector		-		BIN_P
X4	SMA-connector		-		AIN_P
X5	SMA-connector		-		AOUT_P

12. Package outline

HVQFN32: plastic thermal enhanced very thin quad flat package; no leads; 32 terminals; body 5 x 5 x 0.85 mm **SOT617-1**



DIMENSIONS (mm are the original dimensions)

UNIT	$A^{(1)}$ max.	A_1	b	c	$D^{(1)}$	D_h	$E^{(1)}$	E_h	e	e_1	e_2	L	v	w	y	y_1
mm	1	0.05 0.00	0.30 0.18	0.2	5.1 4.9	3.25 2.95	5.1 4.9	3.25 2.95	0.5	3.5	3.5	0.5 0.3	0.1	0.05	0.05	0.1

Note

1. Plastic or metal protrusions of 0.075 mm maximum per side are not included.

OUTLINE VERSION	REFERENCES				EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	JEITA			
SOT617-1	- - -	MO-220	- - -			~~01-08-08~~ 02-10-18

Fig 32. Package outline SOT617-1 (HVQFN32)

13. Abbreviations

Table 12. Abbreviations

Acronym	Description
ADC	Analog-to-Digital Converter
DIP	Dual In-line Package
EMI	ElectroMagnetic Interference
ESD	ElectroStatic Discharge
GSM	Global System for Mobile Communications
HTOL	High Temperature Operating Life
HVQFN	Heatsink Very-thin Quad Flat-pack No-leads
IF	Intermediate Frequency
LSB	Least Significant Bit
LTE	Long Term Evolution
MMIC	Monolithic Microwave Integrated Circuit
MSB	Most Significant Bit
PCB	Printed-Circuit Board
SMA	SubMiniature version A
WiMAX	Worldwide Interoperability for Microwave Access
W-CDMA	Wideband Code Division Multiple Access

14. Revision history

Table 13. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
BGA7351 v.2	20121219	Product data sheet	-	BGA7351 v.1
Modifications:	• The title has been changed to state a maximum frequency of 500 MHz • Section 1.1 on page 1: the frequency range has been changed to state a maximum frequency of 500 MHz • Section 1.2 on page 1: the frequency range has been changed to state a maximum frequency of 500 MHz • Section 1.2 on page 1: the Moisture sensitivity has been changed to level 1 • Figure 2 on page 5: the name of pin 15 has been corrected • Table 6 on page 6: several changes have been made • Table 10 on page 10: the Moisture sensitivity has been changed to level 1 • Table 11 on page 22: the size of R10 and R13 has been changed to 1206			
BGA7351 v.1	20111228	Product data sheet	-	-

15. Legal information

15.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.nxp.com.

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17. Contents

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